Supporting Information

Guanidinate Ligated Iridium(III) Complexes with Various Cyclometalated Ligands. Synthesis, Structure, and Highly Efficient Electrophosphorescent Properties with a Wide Range of Emission Colour

Virendra Kumar Rai,^a Masayoshi Nishiura,^a Masanori Takimoto,^a and Zhaomin Hou*^{,a}

^aOrganometallic Chemistry Laboratory and Advanced Catalyst Research Team, RIKEN Advanced Science Institute, 2-1 Hirosawa, Wako, Saitama-351-0198, Japan. *Email Address: <u>houz@riken.jp</u>

Figure S1. Phosphorescence life-times of complexes (1-8).





Figure S2. Redox Properties of Complexes (1-8).









OLEDs Characterization of complexes (2-8).







Figure S4. Electroluminescence spectra of complex-**3** at different concentration: inset OLED photograph at 9 volt.



Figure S5. Current density vs current and power efficiency graph of 10% and non-doped(100%) devices of complex (3):



Current density (mA/cm²)

Figure S6. Electroluminescence spectra of complex-4 at 5% doping concentration in CBP at different voltages: inset OLED photograph at 9 volt.



Figure S7. Electroluminescence spectra of complex-5 at 5% doping concentration in CBP at different voltages: inset OLED photograph at 9 volt.



Figure S8. Voltage, current density and luminance (J-V-L) characteristics of device with 5% doping of complex (**5**):



Figure S9. Electroluminescence spectra of complex-6 at 5% doping concentration in CBP at different voltages: inset OLED photograph at 9 volt.



Figure S10. Voltage, current density and luminance (*J-V-L*) characteristics of device with 5% doping of complex (6)





Figure S11. Current and power efficiency graph of device with 5% doping concentration of complex (6)

Figure S12. Electroluminescence spectra of complex-7 at 5% doping concentration in CBP at different voltages: inset OLED photograph at 9 volt.



Figure S13. Electroluminescence spectra of complex-**8** at 5% doping concentration in Alq₃ at different voltages: inset OLED photograph at 9 volt.





Figure S14. Current density, voltage and luminance (*J-V-L*) characteristics of device with 5% doping of complex (**8**)

Figure S15. Current and power efficiency graph of device with 5% doping concentration of complex-8



Figure S16. ORTEP diagrams of Complex 8.



	1	2	4	5	6	7·toluene	8·toluene
Empirical formula	C41H40IrN5	$C_{41}H_{36}F_4IrN_5$	C45H40IrN5	C45H40IrN5O2	C45H40IrN5S2	C52H48IrN5S2	C56H52IrN5
fw	794.98	866.95	843.02	875.02	907.14	907.23	987.23
Temp(K)	173	173	173	173	173	173	173
Cryst syst	monoclinic	triclinic	triclinic	triclinic	monoclinic	triclinic	monoclinic
Space group	$P2_{1}/n$	ΡĪ	ΡĪ	ΡĪ	$P2_{1}/n$	PĪ	<i>C</i> 2/c
Unit cell dimens							
a (Å)	9.3240(14)	9.524(2)	10.378(3)	9.130(8)	9.311(6)	10.335(5)	14.992(7)
b (Å)	38.685(6)	13.963(3)	10.421(3)	17.026(14)	16.719(11)	13.420(7)	29.691(14)
c (Å)	10.3325(15)	14.858(3)	17.146(3)	24.47(2)	24.391(17) Å	17.234(9)	10.583(5)
α (°)	90	73.185(3)	85.018(3)	88.939(13)	90	80.228(7)	90
β (°)	113.095(2)	74.49(3)	81.768(3)	89.100(12)	90.481(12)	77.838(7)	106.707(7)
γ (°)	90	73.671(3)	79.502(4)	87.355(12)	90	72.643(7)	90
V, (Å ³)	3428.2(9)	1777.5(7)	2622(14)	3798(5)	3797(4)	2216(2)	4512(4)
Ζ	4	2	2	4	4	2	4
density(calcd), g/cm ³	1.54	1.62	1.555	1.53	1.587	1.498	1.453
abs coeff, mm ⁻¹	3.913	3.814	3.747	3.56	3.667	3.15	3.003
F(000)	1592	860	844	1752	1816	1008	2000
θ range [°]	2.11-25.06	1.56-25.07	1.99-25.08	1.47-25.34	1.48 to 25.08°	1.60-25.20	1.58 to 25.04
reflns collected	17805	9323	9120	20097	19580	11639	11814
indep reflns(Rint)	6029(0.0603)	6124(0.0436)	6074(0.241)	13267(0.0545)	6694(0.0824)	7659(0.0379)	3972(0.0523)
data/restraints/params	6029/0/428	6124/0/464	6074/0/464	13267/0/955	6694 / 0 / 453	7659/0/546	3972 / 0 / 264
GOF on F ²	1.126	0.994	1.006	1.121	0.655	0.86	0.858
Final R index [I >							0.0245
2σ(I)]	0.0488	0.0288	0.0291	0.0908	0.0422	0.0391	0.0345
Rw	0.1038	0.1126	0.0686	0.2107	0.0609	0.0694	0.0611

Table-SI-1 Summary of Crystallographic Data of 1,2,4-8.